

Features

- 3 kA, 8/20 µs surge capability
- Low clamping voltage under surge
- Bidirectional TVS
- Excellent performance over temperature

Applications

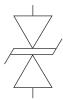
■ High power DC bus protection

Model PTVS3-015C-TH High Current TVS Diode

General Information

The Model PTVS3-015C-TH high current bidirectional TVS diode is designed for use in high power DC bus clamping applications. This device offers bidirectional port protection.

The device is RoHS* compliant and halogen free**. It also meets IEC 61000-4-5 $8/20 \mu s$ current surge requirements.



Absolute Maximum Ratings (@ T_A = 25 °C Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive Standoff Voltage	V _{WM}	15	V
Peak Current Rating per 8/20 μs IEC 61000-4-5	I _{PPM}	3	kA
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _S	-55 to +150	°C
Lead Temperature, Soldering (10 s)		260	°C

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter		Test Conditions	Min.	Тур.	Max.	Unit
I _D	Standby Current	$V_D = V_{WM}$			10	μΑ
V _(BR)	Breakdown Voltage	I _{BR} = 10 mA	16	17.5	19	V
V _C	Clamping Voltage $^{(1)}$ per IEC61000-4-5 (8/20 μ s current waveform)	I _{PP} = 3 kA		28		V
V _(BR)	V _(BR) Temperature Coefficient			0.1		%/°C
С	Capacitance	F = 10 kHz, V _d = 1 Vrms		7.5		nF

⁽¹⁾ V_C measured at the time which is coincident with the peak surge current.

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Specifications are subject to change without notice.

 $^{^{\}star}\,$ RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

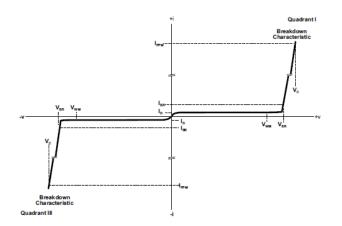
^{**}Bourns considers a product to be "halogen free" if (a) the Bromine (Br) content is 900 ppm or less; (b) the Chlorine (CI) content is 900 ppm or less; and (c) the total Bromine (Br) and Chlorine (CI) content is 1500 ppm or less.

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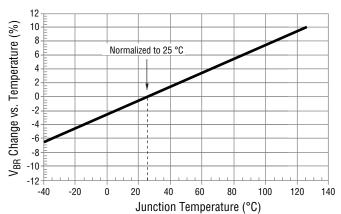
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Performance Graphs

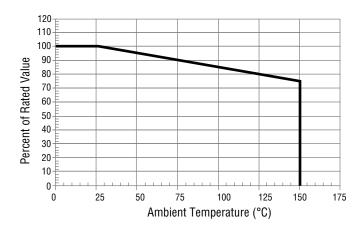
V-I Characteristic



Percentage V_{BR} Change vs. Junction Temperature



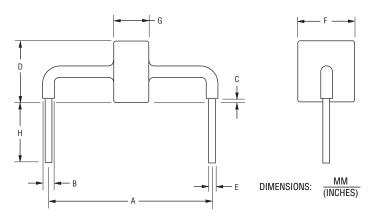
Typical Surge Current Derating



This graph shows the typical device surge current derating versus ambient temperature when subjected to the 8/20 μ s current waveform per the IEC 61000-4-5 specification. This device is not intended for continuous operation at temperatures above 125 °C.

Product Dimensions

Epoxy encapsulation materials conform to UL 94V-0. Silver plated lead finish conforms to the solderability requirements of JESD22-B102, Pb free solder. Package dimensions are shown below:



Dim.	PTVS3-015C-TH
Α	24.15 ± 0.72
	(0.951 ± 0.028)
В	2.40 ± 0.50
	(0.094 ± 0.020)
С	_ 1.75 ± 1.25
	(0.069 ± 0.049)
D	10.80 Max.
	${(0.425)}^{\text{IVIAX}}$
E	1.25 ± 0.05
	(0.049 ± 0.002)
F	9.30 Max.
	(0.366) Wax.
G	4.00 Max.
	(0.157) Max.
Н	6.00 ± 1.00
	$\overline{(0.236 \pm 0.039)}$

Typical Part Marking

PTVS3-015C-TH3015

